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Please note. As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild questions@onsemi.com.

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December 2013

74VCX08 Low Voltage Quad 2-Input AND Gate with 3.6V Tolerant **Inputs and Outputs**

Features

- 1.2V to 3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- - 2.8ns max. for 3.0V to 3.6V V_{CC}
- Power-off high impedance inputs and outputs
- Static Drive (I_{OH}/I_{OL})
 - ±24mA @ 3.0V V_{CC}
- Uses proprietary Quiet Series[™] noise/EMI reduction
- Latchup performance exceeds 300mA
- ESD performance:
 - Human body model > 2000V
 - Machine model > 250V
- Leadless DQFN package

General Description

The VCX08 contains four 2-input and tes. This product is designed for low voltage (2V to 3 V) V_{CC} application cations with I/O compatile .y up to 6V.

Ordering Ir Juna n

■ t _{PD} :		cations with 1/O compatible, by up to 5v.
 2.8ns max. for 3.0 	V to 3.6V V_{CC}	The VCX08 is for rice of with an advanced CMOS
■ Power-off high impe		outputs technology to achie hig spe operation while main-
		taining low Cr S por r dis pation
■ Static Drive (I _{OH} /I _{OL})		
±24mA @ 3.0V V		
Uses proprietary Qu circuitry	iet Series™ noise	e/EMI reduction A A MENDER OR MATION OR
■ Latchup performanc	e exceeds 300mA	
■ ESD performance:		1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
•	al > 2000\/	
 Human body mod 		NV IR ON"
Machine model >	250V	
■ Leadless DQFN pag	kage	10,50
Ordering Ir Jun	al 'n	RENTH FO.
	Package	
Corn mb	Number	Package Description
'VCX0 1	M14A	1/2-Lead Smail Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150"
1VCX0 1	√M14A C	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
	12/0-	Narrow
74V JdBQX ⁽¹⁾	M14A MLF14A	Narrow 1 4-Terminal Depopulated Quad Very-Thin Flat Pack No Leads (DQFN),
74V JdBQX ^(†)	MLF14A	Narrow 1.7-Terminal Depopulated Quad Very-Thin Flat Pack No Leads (DQFN), DEDEC MO-241, 2.5 x 3.0mm
	12/0-	Narrow 1 4-Terminal Depopulated Quad Very-Thin Flat Pack No Leads (DQFN),

Note:

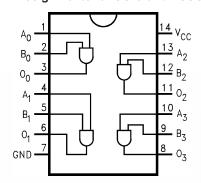
1. DQFN package available in Tape and Reel only.

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.

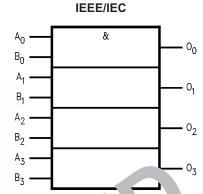
All packages are lead free per JEDEC: J-STD-020B standard.

Connection Diagrams

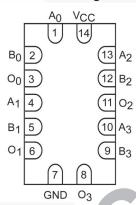
Pin Assignments for SOIC and TSSOP

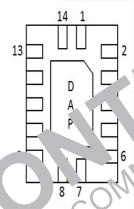


Logic Symbol



Pad Assignments for DQFN





(Tor View

Postom view)

Pin Descr. "

r 'an 3	escription
. B _n	Inputs
On	Outputs
DAP	No Connect

Note: DAP (Die Attach Pad)

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	-0.5V to +4.6V
V _I	DC Input Voltage	-0.5V to 4.6V
Vo	DC Output Voltage	
	HIGH or LOW State ⁽²⁾	-0.5V to V _{CC} +0.5V
	V _{CC} = 0V	-0.5V to +4.6V
I _{IK}	DC Input Diode Current, V _I < 0V	-50mA
I _{OK}	DC Output Diode Current	A 7 75
	$V_{O} < 0V$	-50mA
	V _o > V _{cc}	+50mA
I _{OH} / I _{OL}	DC Output Source/Sink Current	+50mA
I _{CC} or GND	DC V _{CC} or Gound Current per Supply Pin	±100mA
T _{STG}	Storage Temperature Range	-35°C to +150°C

Note:

2. IO Absolute Maximum Rating must be observe

Recommended Operation of the Constitution of t

The Recommended Operating Conditions to Die Lefines the conditions for actual device operation. Recommended operating conditions are seed the ensured operating conditions are seed to be ensured by the datasheat specifications. Fairchild does not recommend exceeding the ensured absolute maximum ratings.

Symbol	Parameter	Rating
V _{CC}	oply Operating	1.2V to 3.6V
•	Inp *1/ .age	-0.3V to 3.6V
V_0	utput Vollage, HIGH or LOW State	0V to V _{CC}
1/10	Output Current	A
	$V_{CC} = 3 \text{ OV to } 3.6 \text{ V}$	±24mA
	$V_{CC} = 2.3V \text{ to } 2.7V$	±18mA
	$V_{CC} = 1.65$ (to 2.3V	±6mA
5	V _{CC} =).4 V to 1.6V	±2mA
·	$V_{CC} = 1.2V$	±100μA
T _A	Free Air Operating Temperature	-40°C to +85°C
Δt / ΔV	Minimum Input Edge Rate, $V_{IN} = 0.8V$ to 2.0V, $V_{CC} = 3.0V$	10ns/V

Note:

3. Floating or unused inputs must be held HIGH or LOW

DC Electrical Characteristics

Symbol	Parameter	V _{CC} (V)	Conditions	Min	Max	Units
V _{IH}	HIGH Level Input Voltage	2.7–3.6		2.0		V
		2.3–2.7		1.6		
		1.65–2.3		0.65 × V _{CC}		
		1.4–1.6		0.65 × V _{CC}		
		1.2		0.65 × V _{CC}		
V _{IL}	LOW Level Input Voltage	2.7-3.6			0.8	V
		2.3–2.7			0.7	
		1.65–2.3			$0.35 \times V_{CC}$	
		1.4–1.6			0.3. V _{CC}	
		1.2			0.05 \ / _{CC}	.6
V _{OH}	HIGH Level Output Voltage	2.7-3.6	$I_{OH} = -100 \mu A$	(0-0)		V
		2.7	$I_{OH} = -12mA$		11	D
		3.0	I _{OH} = -18mA	2.	SAA	
		3.0	I _{OH} = -24mA	2.2	7/	
		2.3–2.7	I _{OH} = -1t	V _{CC} - C.2		
		2.3	I = mA	20	1-12	7
		2.3	1 = -1. A	1.8	10	
		2	I _{Oi} = -18n _i A	17	1/1	
		~5-2.	I _{OH} = -100µA	V _{CC} - 02		
		65	$I_{OH} = - \Im i \gamma_i A$	1.25		-
		1.4 \.6	$I_{OH} = -100 \mu A$	V _{CC} - 0.2		
		1.4	$I_{OH} = -2 \text{rnA}$	1.05		
		1.2	Ι _{ΟΗ} = · -100μΑ	V _{CC} - 0.2		
V _{OL}	LOVel C nut V age	2.7-3.6	I _C . = 100μ.(0.2	V
		2.7	$I_{OL} = 12 \text{mA}$		0.4	-
	70,	3.0	J _{OL} = 18mA		0.4	
	ICE SEAS	3.0	I _{OL} = 24mA		0.55	
	12,03	2 32.7	I _{OL} = 100μA		0.2	
		2.3	I _{OL} = 12mA		0.4	
	The Bridge	2.3	I _{OL} = 18mA		0.6	
	REPRE	1.65–2.3	$I_{OL} = 100 \mu A$		0.2	
SVI		1.65	I _{OL} = 6mA		0.2	
	RV	1.4–1.6	I _{OL} = 100μA		0.2	-
		1.4	$I_{OL} = 2mA$		0.35	
		1.2	I _{OL} = 100μA		0.05	
l _l	Input Leakage Current	1.2–3.6	$0 \le V_1 \le 3.6V$		±5.0	μA
I _{OFF}	Power-OFF Leakage Current	0	$0 \le (V_I, V_O) \le 3.6V$		10	μA
I _{CC}	Quiescent Supply Current	1.2–3.6	$V_I = V_{CC}$ or GND		20	μA
			$V_{CC} \le V_I \le 3.6V$		±20	
Δl _{CC}	Increase in I _{CC} per Input	2.7–3.6	$V_{IH} = V_{CC} - 0.6V$		750	μA

AC Electrical Characteristics⁽⁴⁾

				T _A = -40°C to +85°C			Figure
Symbol	Parameter	V _{CC} (V)	Conditions	Min.	Max.	Units	Number
t _{PHL} , t _{PLH}	Propagation Delay	3.3 ± 0.3	$C_L = 30 pF, R_L = 500 \Omega$	0.6	2.8	ns	Fig. 1
		2.5 ± 0.2		0.8	3.7		Fig. 2
		1.8 ± 0.15		1.0	7.4		
		1.5 ± 0.1	$C_L = 15pF, R_L = 2k\Omega$	1.0	14.8		Fig. 3
		1.2		1.5	37.0		Fig. 4
t _{OSHL} , t _{OSLH}	Output to Output	3.3 ± 0.3	$C_L = 30 pF, R_L = 500 \Omega$		0.5		
	Skew ⁽⁵⁾	2.5 ± 0.2			0.5		
		1.8 ± 0.15			.15		1,5
		1.5 ± 0.1	$C_L = 15pF, R_L = 2k\Omega$				OF
		1.2	4		5	2	

Note:

- 4. For $C_1 = 50$ pF, add approximately 300ps to the AC Maximum ocific.
- propagation delay for any two separate 5. Skew is defined as the absolute value of the difference be seen the outputs of the same device. The specification applier any true switching in the same direction, either HIGH-to-LOW (tosh) or LOW-to-HIGH (tosh).

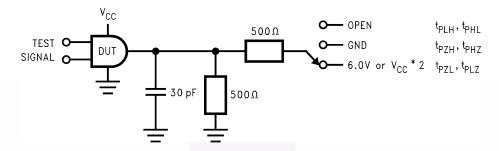
Dynamic Switching Characterismo.

		"VIII	10,100	$T_A = 25^{\circ}C$	
Symbol	am. pr	V _{CC} (V)	Conditions	Typical	Unit
V _{OLP}	Quiet Ou It Dynamic Peak VCC		$C_L = 30 \text{pr} V_{IH} = V_{CC}$	0.25	V
	C	2.5	V _{I.} = 0V	0.6	
		3.3		0.8	
	Qu' fut Dynamic Valley Vol	1.8	$C_L = 30pF, V_{IH} = V_{CC},$	-0.25	V
	15,56,4	2.5	$V_{IL} = 0V$	-0.6	
	CE, CK, CK,	3.3		-0.8	
V_{OHV}	Quiet Outrut Dynamic Valley V _{OH}	1.8	$C_L = 30pF, V_{IH} = V_{CC},$	1.5	V
OE)	22	2.5	$V_{IL} = 0V$	1.9	
CV		3.3		2.2	

Capacitance

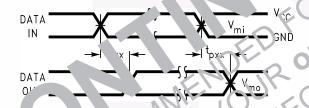
			T _A = +25°C	
Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance	$V_{I} = 0V \text{ or } V_{CC}, V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$	6.0	pF
C _{OUT}	Output Capacitance	$V_{I} = 0V \text{ or } V_{CC}, V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$	7.0	pF
C _{PD}	Power Dissipation Capacitance	$V_I = 0V \text{ or } V_{CC}, f = 10MHz, V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$	20.0	pF

AC Loading and Waveforms (V_{CC} 3.3V \pm 0.3V to 1.8V \pm 0.15V)



Test	Switch
t _{PLH} , t _{PHL}	Open

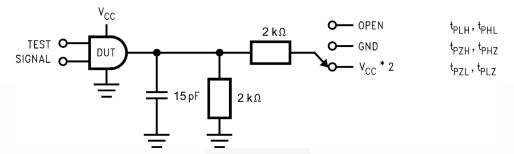
Figure 1. AC Test Circuit



		are a	Vcc	
	lor ""	3.3V ± 0.3V	2.5V < 0.2V	1.8V ± 0.15V
	V _{mi}	1.5V	V _{CC} / 2	V _{CC} / 2
1	Vino	1.5V	V _{CC} /2	V _{CC} / 2

Figure 7. Waveform for Inverting and Non-inverting Functions

AC Loading and Waveforms (V_{CC} 1.5 \pm 0.1V to 1.2V)



Test	Switch
t _{PLH} , t _{PHL}	Open
t _{PZL} , t _{PLZ}	$V_{CC} \times 2$ at $V_{CC} = 1.5V \pm 0.1V$
t _{PZH} , t _{PHZ}	GND

Figure 3. AC Test Circu



RAN	Vcc
Symbol	1.5V ± 0.1V
V _{mi}	V _{CC} / 2
V _{mo}	V _{CC} / 2

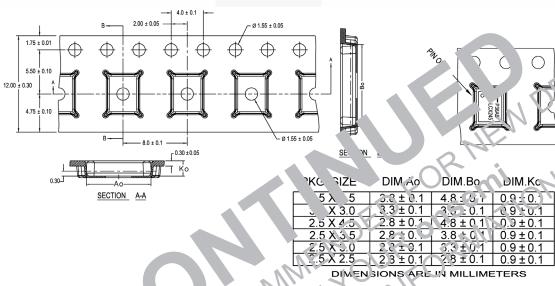
Figure 4. Wavelorm for Inverting and Non-Inverting Functions

Tape and Reel Specification

Tape Format for DQFN

Package Designator	Tape Section	Number of Cavities	Cavity Status	Cover Tape Status	
BQX	Leader (Start End)	125 (Typ.)	Empty	Sealed	
	Carrier	3000	Filled	Sealed	
	Trailer (Hub End)	75 (Typ.)	Empty	Sealed	

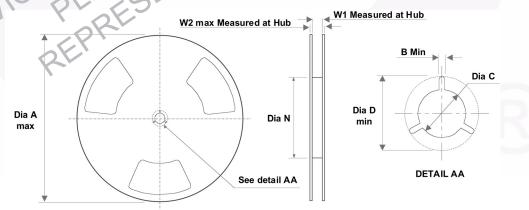
Tape Dimensions inches (millimeters)



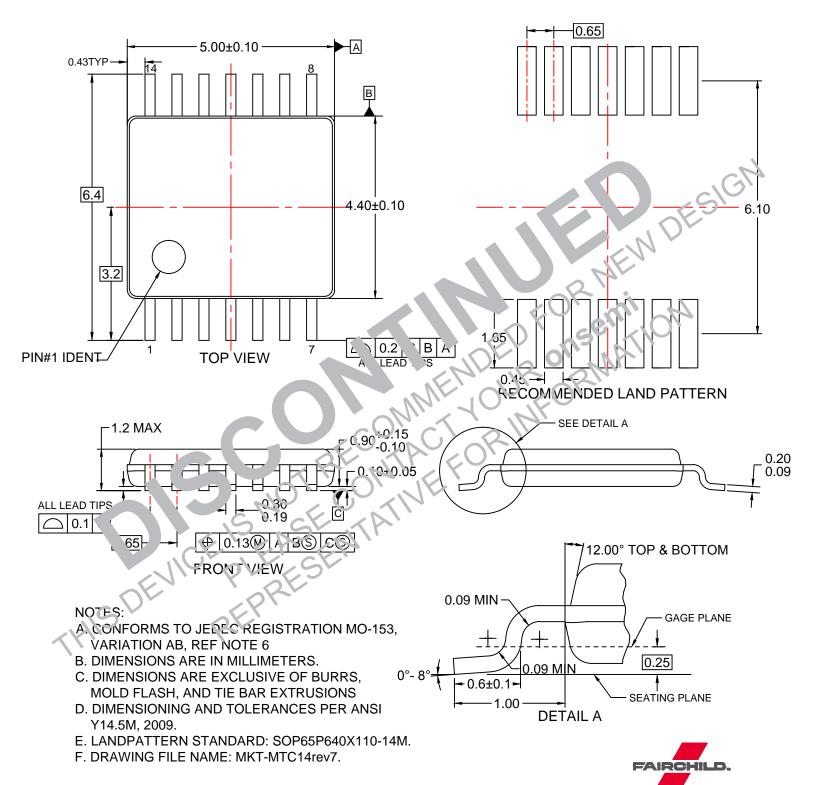
NOTES: unless otherwisconified

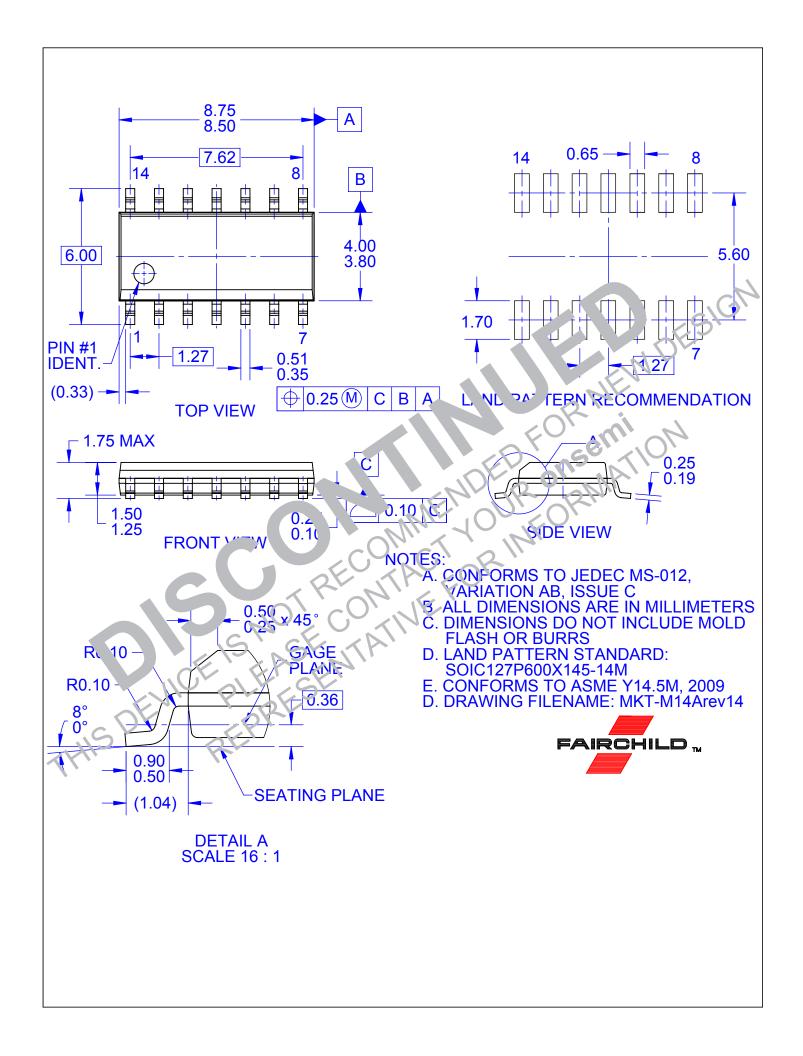
- 1. Cummulative pitc for feeding how a cavifies (chip pockets) not to exceed 0.000[0.20] over 10 pitch span.
- 2. Smallest allowable ending reus.
- 3. Thru h made ca is cer red within carity.
- 4. Tolerable is 10002 these timensions on all 125 m tapes.
- 5. and don a plang 0 120[0.30] above the bottom of the pocket.
- 6. k heasured from a plane on the inside bottom of the pocket to the top surface of the carrier.
 - Pour tipe additive to spir cket hole measured as true position of pocket. Not pocket hole.
- ont, ing dimension is millimeter. Die hension in incher rounded.

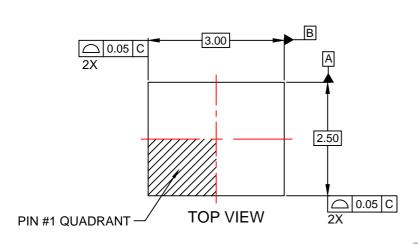
Ree. __nensions inches (milirieters)

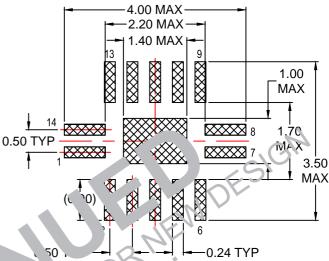


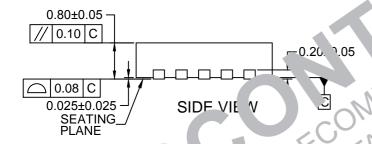
Tape Size	Α	В	С	D	N	W1	W2
12mm	13.0 (330.0)	0.059 (1.50)	0.512 (13.00)	0.795 (20.20)	2.165 (55.00)	0.488 (12.4)	0.724 (18.4)



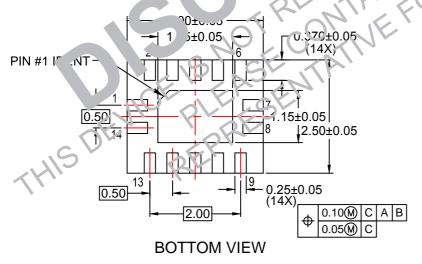












NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MO-241, VARIATION AA
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.
- D. LAND PATTERN RECOMMENDATION IS EXISTING INDUSTRY LAND PATTERN.
- E. DRAWING FILENAME: MKT-MLP14Arev2.





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